NSN 5962-01-303-3548

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View Online at https://aerobasegroup.com/nsn/5962-01-303-3548

Overall Height:

Between 0.220 inches and 0.360 inches

Body Length:

Between 2.370 inches and 2.430 inches

Body Width:

Between 0.550 inches and 0.610 inches

Body Height:

Between 0.030 inches and 0.170 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and w/enable and electrostatic sensitive and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

44 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

120.00 nanoseconds propagation delay time, low to high level output and 120.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

48 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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